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CONFIRMATION NO. 3218

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APPLICANTS

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\*\* CONTINUING DATA ..... <sup>YES</sup> <sub>m</sub>

This application is a CON of 09/291,538 04/14/1999 ABN, which is a Div of 08/911,505  
 Pat No. 6,274,414.

\*\* FOREIGN APPLICATIONS ..... <sup>YES</sup> <sub>m</sub>

JAPAN HEI 8-217424 08/19/1996

IF REQUIRED, FOREIGN FILING LICENSE GRANTED  
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Foreign Priority claimed 35 USC 119 (a-d) conditions met	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance <sub>m</sub>	STATE OR COUNTRY JAPAN	SHEETS DRAWING 25	TOTAL CLAIMS 5	INDEPENDENT CLAIMS 1
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Verified and Acknowledged  
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TITLE  
 Laser anneal method of a semiconductor layer

☐ All Fees